

Features

- Trench Power LV MOSFET Technology
- · Excellent Package for Heat Dissipation
- High Density Cell Design for Low R_{DS(on)}
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

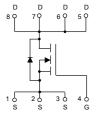
- Operating Junction Temperature Range : -55°C to +175°C
- Storage Temperature Range: -55°C to +175°C
- Thermal Resistance: 5°C/W Junction to Case

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage		V _{DS}	30	V
Gate-Source Volltage		V _{GS}	±20	V
Continuous Drain Current	T _C =25°C	1	50	Α
	T _C =100°C	l _D	35	Α
Pulsed Drain Current (Note 2	I _{DM}	190	Α	
Single Pulse Avalanche Energy (Note 3)		E _{AS}	225	mJ
Total Power Dissipation	T _C =25°C	P _D	30	W
	T _C =100°C	I D	15	W

Note:

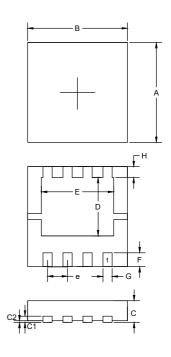
- 2.Pulse Test; Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- $3.T_J=25$ °C, $V_{DS}=30V$, $V_{DD}=25V$, $V_{GS}=10V$, L=1mH.

Internal Structure



N-CHANNEL MOSFET

DFN3333



DIMENSIONS						
DIM INCHES		HES	MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.126	0.130	3.20	3.30		
В	0.126	0.130	3.20	3.30		
С	0.030	0.033	0.75	0.85		
C1	0.007	0.009	0.18	0.22		
C2		0.002		0.05		
D	0.071	0.079	1.80	2.00		
Е	0.087	0.098	2.20	2.50		
F	0.016	0.020	0.40	0.50		
G	0.010	0.014	0.25	0.35		
Н	0.012	0.016	0.30	0.40		
е	0.024	0.028	0.60	0.70		

 $^{1.}R_{\theta JA}$ is the Sum of the Junction-to-Case and Case-to-Ambient Thermal Resistance, Where the Case Thermal Reference is Defined as The Solder Mounting Surface of the Drain Pins. $R_{\theta JC}$ is Guaranteed by Design, While $R_{\theta JA}$ is Determined by the Board Design. The Maximum Rating Presented Here is Based on Mounting on a 1 in² pad of 2oz Copper.

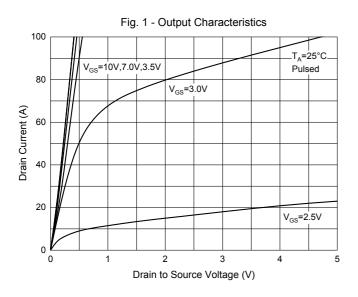


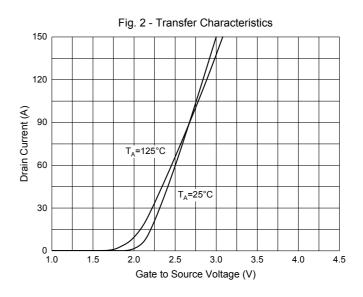
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

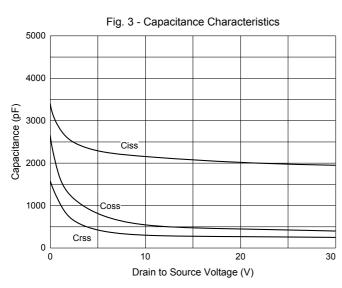
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	30			V
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V			1	μΑ
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1	1.5	2.5	V
Drain-Source On-Resistance	_	V _{GS} =10V, I _D =15A		4.9 6		0
	R _{DS(on)}	V _{GS} =4.5V, I _D =15A		6.3	8	mΩ
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A			1.2	V
Continuous Body Diode Current	Is				50	Α
Dynamic Characteristics						
Input Capacitance	C _{iss}			2150		pF
Output Capacitance	C _{oss}	V _{DS} =15V,V _{GS} =0V,f=1MHz		435		
Reverse Transfer Capacitance	C _{rss}			252		
Total Gate Charge	Qg			52.8		nC
Gate-Source Charge	Q_{gs}	V _{DS} =15V,V _{GS} =10V,I _D =20A		12.3		
Gate-Drain Charge	Q_{gd}			10.8		
Turn-On Delay Time	t _{d(on)}			9		
Turn-On Rise Time	t _r	V_{GS} =10V, V_{DD} =20V, I_{D} =4A, R_{L} =1 Ω		15.5		ns
Turn-Off Delay Time	t _{d(off)}	R_{GEN} =3 Ω		29		
Turn-Off Fall Time	t _f			9		
Gate-Source Leakage Current	I _{GSS}	L _25A_di/dt_100A/ug		28		nC
Zero Gate Voltage Drain Current	I _{DSS}	I _F =25A, di/dt=100A/μs		27		ns

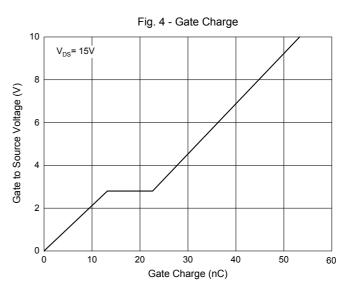


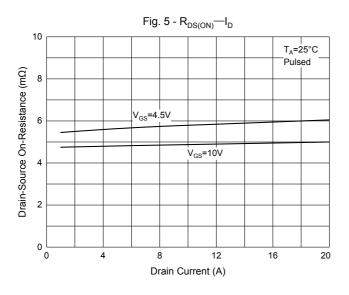
Curve Characteristics

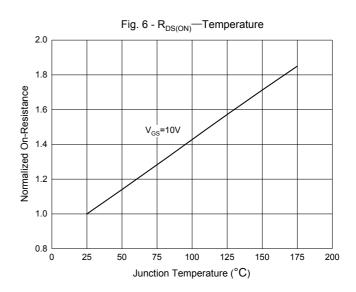














Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 5Kpcs/Reel

Note: Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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